

JANTXV2N6849U

Request a Quote

JANTXV2N6849U Information

Heisener.com	Part Number	JANTXV2N6849U	
		Microsemi Corporation	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET P-CH 100V 6.5A	
	Package	18-BQFN Exposed Pad	
	_	For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JANTXV2N6849U Specifications

Manufacturer Part Number	JANTXV2N6849U
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	18-BQFN Exposed Pad
Series	Military, MIL-PRF-19500/564
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	6.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	34.8nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	800mW (Ta), 25W (Tc)
Rds On (Max) @ Id, Vgs	320 mOhm @ 6.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	18-ULCC (9.14x7.49)
Package / Case	18-BQFN Exposed Pad
	Report errors?

JANTXV2N6849U Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

JANTXV2N6849U Payment Methods





If you have any question about JANTXV2N6849U, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com